

Customer No. 31561 Docket No. 9003-US-PA Application No.: 10/709,008

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Applicant

: Chang

Application No.

: 10/709,008

Filed

: April 7, 2004

For

: METHOD OF FABRICATING A POLYSILICON THIN

FILM

Examiner

Art Unit

: 2812

INFORMATION DISCLOSURE STATEMENT

ASSISTANT COMISSIONER FOR PATENTS Arlington, VA22202

Enclosed is a PTO Form 1449 listing 3 reference(s), copy of which is attached. Applicant submits the reference(s) in compliance with his duty of disclosure pursuant to 37 CFR § 1.56 and 1.97. The Examiner is requested to make the citation(s) of official record.

This IDS is being submitted before the first Office Action. Thus, it is believed no fee is due.

The submission of the reference(s) should not be interpreted as admitting them as prior art.

Respectfully Submitted,

JIANQ CHYUN Intellectual Property Office

Date:

t 3,0004

By:

Registration No.: 46,863

Please send future correspondence to:

7F. -1, No. 100, Roosevelt Rd.,

Sec. 2, Taipei 100, Taiwan, R.O.C.

Tel: 886-2-2369 2800

Fax: 886-2-2369 7233 / 886-2-2369 7234

E-MAIL: BELINDA@JCIPGroup.com.tw; USA@JCIPGroup.com.tw

AUG O L TOTAL STATE OF THE PATENT AND TRADEL INFORMATION DISCLOSURE STATE

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICATION

| ATTY. DOCKET NO.:9003-US-PA | APPLICATION NO.: 10/709,008 | | |
|-----------------------------|-----------------------------|--|--|
| APPLICANT: Chang | | | |
| FILING DATE: April 7, 2004 | GROUP 2812 | | |

U.S. PATENT DOUCMENTS

| C.S. TATENT DOCUMENTS | | | | | | |
|-----------------------|--------------------|------------|--------------|-------|----------|------------------------------------|
| EXAMINER INITIAL | DOCUMENT NUMBER | DATE | NAME | CLASS | SUBCLASS | FIILNG DATE (IF APPROPRIATE) |
| | 2002/0115245 | 2002/08/22 | Chang et al. | 438 | 166 | 2001/02/21 |
| | | | , | | | |
| | | | | | | |

FOREIGN PATENT DOCUMENTS

| | | | | TELLITE DOCUMENTED | | | |
|----------|--------|-----------------|------|--------------------|-------|----------|------------------|
| EXAMINER | | DOCUMENT NUMBER | DATE | COUNTRY | CLASS | SUBCLASS | FIILNG DATE |
| INITIAL | | | | | | | (IF APPROPRIATE) |
| | | | | | | | ļ. |
| | | | | | | | |
| | | | | | | | |
| | | | | | | | |
| | T | | | | | | |
| | | | | | | | |
| | | | | | | | |
| | \top | | | | | | |
| | | | | | | | |

| EXAMINER INITIAL | OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.) |
|---------------------|--|
| | Brotherton et al., Excimer-Laser-Annealed Poly-Si Thin-Film Transistors in IEEE Transactions On Electron |
| | Devices, Vol. 40, No. 2, pp. 407-413, February 1993. |
| | Zeng et al., A Novel Two-Step Laser Crystallization Technique for Low- Temperature Poly-Si TFTs in |
| | IEEE Transactions On Electron Devices, Vol. 48, No. 5, pp. 1008-1010, May 2001. |
| | |
| | |

| EXAMINER | DATE CONSIDERED |
|----------|-----------------|
| | |

EXAMINER: INITIAL IF CITATION CONSIDERED, WHETHER OR NOT CITATION IS IN CONFORMANCE WITH MPEP 609; DRAW LINE THROUGH CITATION IF NOT IN CONFORMANCE AND NOT CONSIDERED. INCLUDE COPY OF THIS FORM WITH NEST COMMUNICATION TO APPLICANT.